Supplementary information

Edge-Oriented MoS₂ Supported on Nickel/Carbon Core-Shell Nanospheres for Enhanced Hydrogen Evolution Reaction Performance

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Fig. S1. Deconvolution Curve of Carbon region in raman spectrum of Ni/C/MoS₂.



Fig. S2. EDS spectrum for C/MoS_2 etched by HCl to measure nickel residual.



Fig. S3. Cyclic voltammetry of Ni/C at a potential range without faradic current to measure capacitive current with different scan rates.



Fig. S4. TEM images of Ni/C/MoS₂. a) Morphology of Ni/C/MoS₂ before 9000 s *i-t* amperometric testing; b) Morphology of Ni/C/MoS₂ after 9000 s *i-t* amperometric testing.

El	AN	Series	unn. C [wt.%]	norm. C [wt.%]	Atom. C [at.%]	Error [%]
C Mo S O Ni Se	6 42 16 8 28 34	K-series L-series K-series K-series L-series	33.39 26.88 18.33 14.67 2.89 0.10	34.69 27.92 19.04 15.24 3.00 0.10	60.44 6.09 12.43 19.94 1.07 0.03	4.6 1.0 0.7 2.1 0.1 0.0
200000		Total:	96.25	100.00	100.00	

Table S1. EDS elements table for C/MoS_2 etched by HCl to measure nickel residual